



### Typical Applications

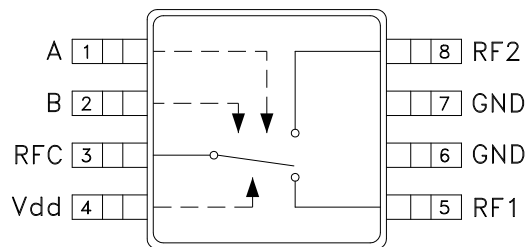
The HMC174MS8(E) is ideal for:

- Infrastructure & Repeaters
- Cellular/3G & WiMAX
- Portable Wireless
- LNA Protection
- Automotive Telematics
- Test Equipment

### Features

- Low Insertion Loss: 0.5 dB
- High Input IP3: +60 dBm
- Positive Control: 0/+3V to 0 /+8V
- High RF power Capability
- MSOP - 8 SMT package, 14.8 mm<sup>2</sup>

### Functional Diagram



### General Description

The HMC174MS8 & HMC174MS8E are low-cost SPDT switches in 8-lead MSOP packages for use in transmit-receive applications which require very low distortion at high signal power levels. The device can control signals from DC to 3 GHz and is especially suited for cellular/3G and WiMAX applications with only 0.5 dB loss. The design provides exceptional intermodulation performance; providing a +60 dBm third order intercept at 8 Volt bias. RF1 and RF2 are reflective shorts when "OFF". On chip circuitry allows single positive supply operation at very low DC current with control inputs compatible with CMOS and most TTL logic families.

### Electrical Specifications, $T_A = +25^\circ \text{C}$ , $V_{dd} = +5 \text{ Vdc}$ , 50 Ohm System

Parameter	Frequency	Min.	Typ.	Max.	Units
Insertion Loss	DC - 1.0 GHz		0.4	0.7	dB
	DC - 2.0 GHz		0.5	0.8	dB
	DC - 2.5 GHz		0.8	1.1	dB
	DC - 3.0 GHz		1.3	1.8	dB
Isolation	DC - 1.0 GHz	21	26		dB
	DC - 2.0 GHz	21	26		dB
	DC - 2.5 GHz	18	23		dB
	DC - 3.0 GHz	15	20		dB
Return Loss	DC - 1.0 GHz		25		dB
	DC - 2.0 GHz		20		dB
	DC - 2.5 GHz		15		dB
	DC - 3.0 GHz		12		dB
Input Power for 1 dB Compression	0.5 - 1.0 GHz	32	36		dBm
	0.5 - 3.0 GHz	32	36		dBm
Input Third Order Intercept	0.5 - 1.0 GHz	55	60		dBm
	0.5 - 3.0 GHz	49	56		dBm
Switching Characteristics	DC - 3.0 GHz				
			10		ns
			24		ns

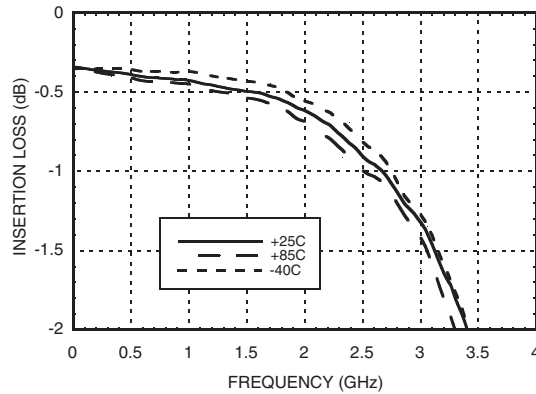
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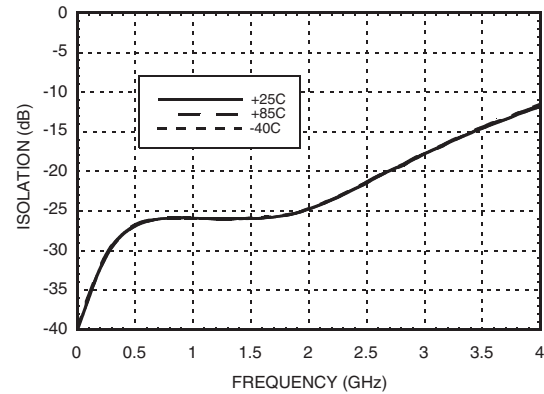


**GaAs MMIC T/R SWITCH  
DC - 3 GHz**

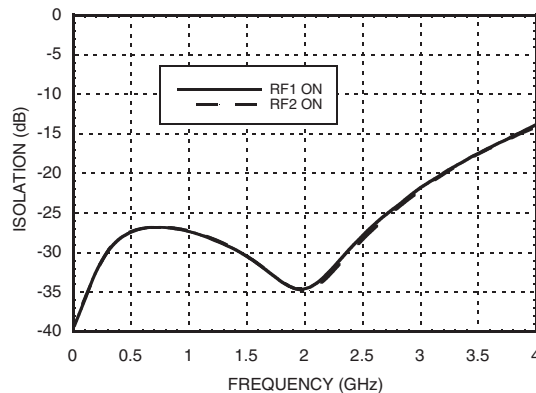
**Insertion Loss**



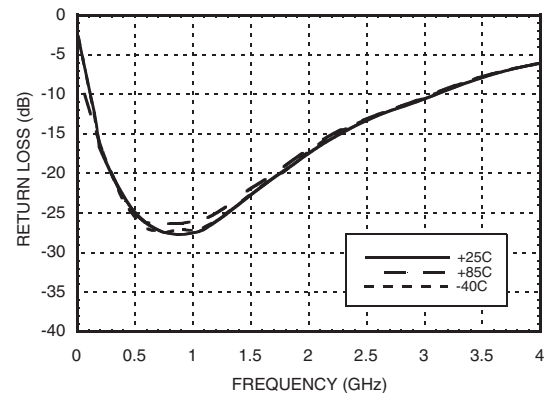
**Isolation Between RFC & RF1/RF2**



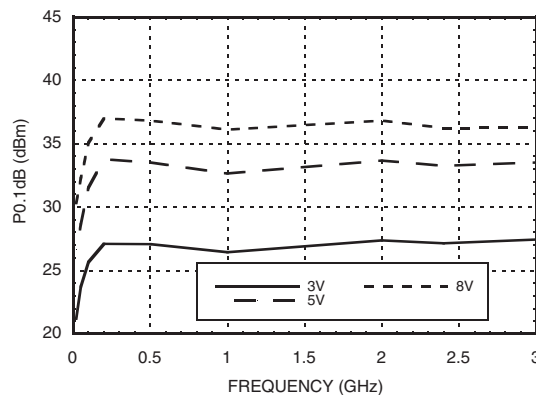
**RF1 to RF2 Isolation**



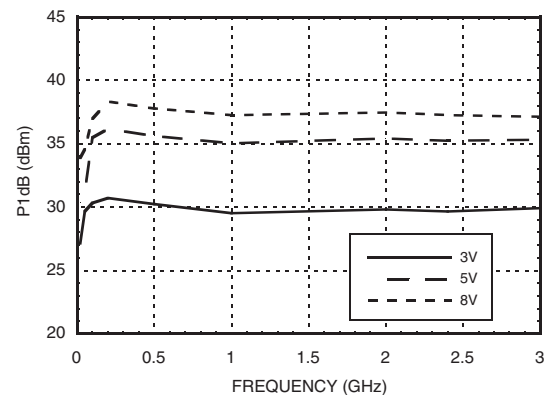
**Return Loss**

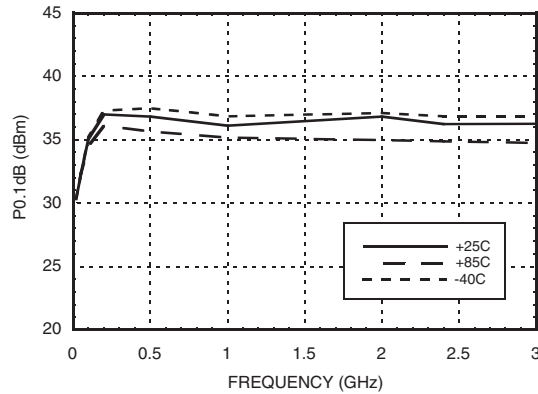
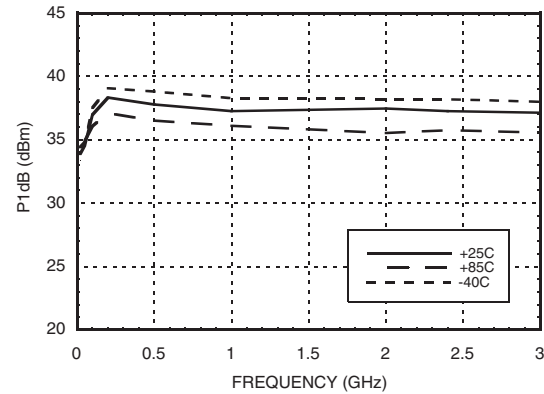
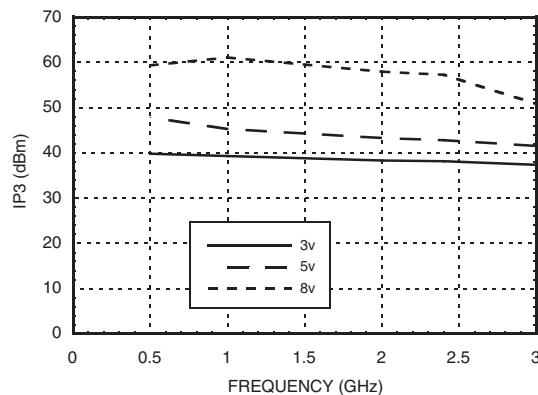
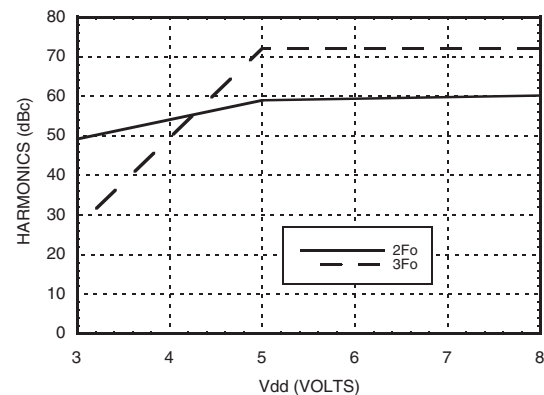
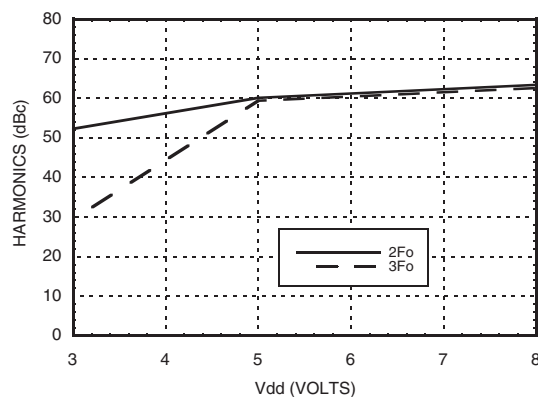


**Input P0.1dB vs. Vdd**



**Input P1dB vs. Vdd**



**Input P0.1dB vs. Temperature**

**Input P1dB vs. Temperature**

**Input Third Order Intercept**

**2nd & 3rd Harmonics @ 900 MHz**

**2nd & 3rd Harmonics @ 1900 MHz**

**Absolute Maximum Ratings**

Bias Voltage Range (Vdd)	-0.2 to +10 Vdc
Control Voltage Range (A & B)	-0.2 to +Vdd Vdc
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

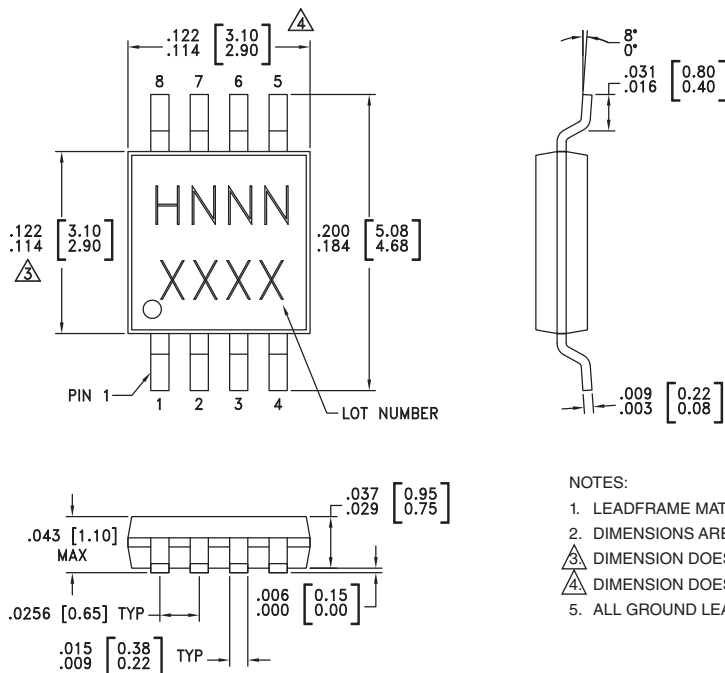


**ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS**

**Truth Table \*Control Input Voltage Tolerances are  $\pm 0.2$  Vdc**

Bias	Control Input*		Bias Current	Control Current		Signal Path State	
Vdd (Vdc)	A (Vdc)	B (Vdc)	Idd (uA)	Ia (uA)	Ib (uA)	RF to RF1	RF to RF2
3	0	0	30	-15	-15	OFF	OFF
3	0	Vdd	25	-25	0	ON	OFF
3	Vdd	0	25	0	-25	OFF	ON
5	0	0	110	-55	-55	OFF	OFF
5	0	Vdd	115	-100	-15	ON	OFF
5	Vdd	0	115	-15	-100	OFF	ON
10	0	0	380	-190	-190	OFF	OFF
10	0	Vdd	495	-275	-220	ON	OFF
10	Vdd	0	495	-220	-275	OFF	ON
5	-Vdd	Vdd	600	-600	225	ON	OFF
5	Vdd	-Vdd	600	225	-600	OFF	ON

## Outline Drawing



## Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[3]</sup>
HMC174MS8	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 <sup>[1]</sup>	H174 XXXX
HMC174MS8E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 <sup>[2]</sup>	H174 XXXX

[1] Max peak reflow temperature of 235 °C

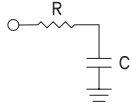

[2] Max peak reflow temperature of 260 °C

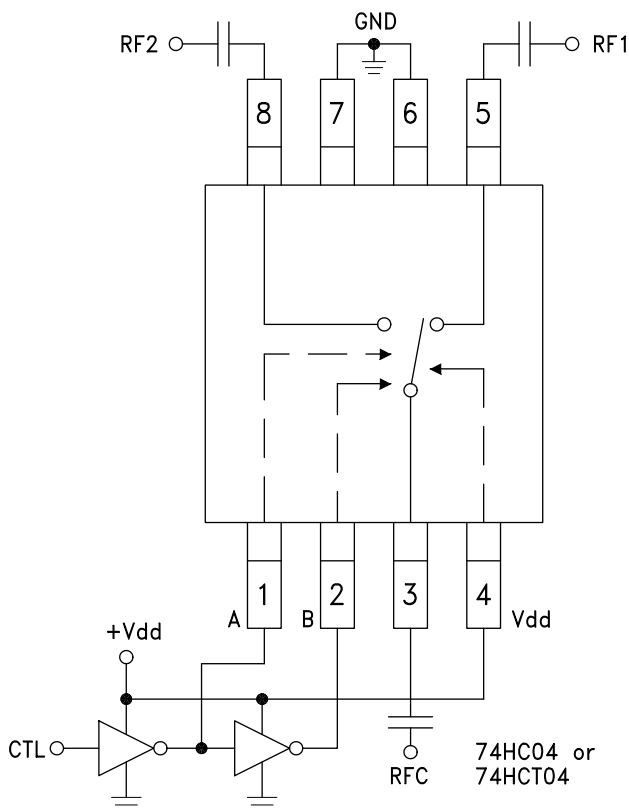
[3] 4-Digit lot number XXXX

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**GaAs MMIC T/R SWITCH  
DC - 3 GHz**
**Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1	A	See truth table and control voltage table.	
2	B	See truth table and control voltage table.	
3, 5, 8	RFC, RF1, RF2	This pin is DC coupled and matched to 50 Ohm. Blocking capacitors are required.	
4	Vdd	Supply Voltage.	
6, 7	GND	This pin must be connected to RF/DC ground.	

**Typical Application Circuit**

**Notes:**

1. Set logic gate and switch Vdd = +3V to +5V and use HCT series logic to provide a TTL driver interface.
2. Control inputs A/B can be driven directly with CMOS logic (HC) with Vdd of 3 to 8 Volts applied to the CMOS logic gates and to pin 4 of the RF switch.
3. DC Blocking capacitors are required for each RF port as shown. Capacitor value determines lowest frequency of operation.
4. Highest RF signal power capability is achieved with V set to +8V. The switch will operate properly (but at lower RF power capability) at bias voltages down to +3V.

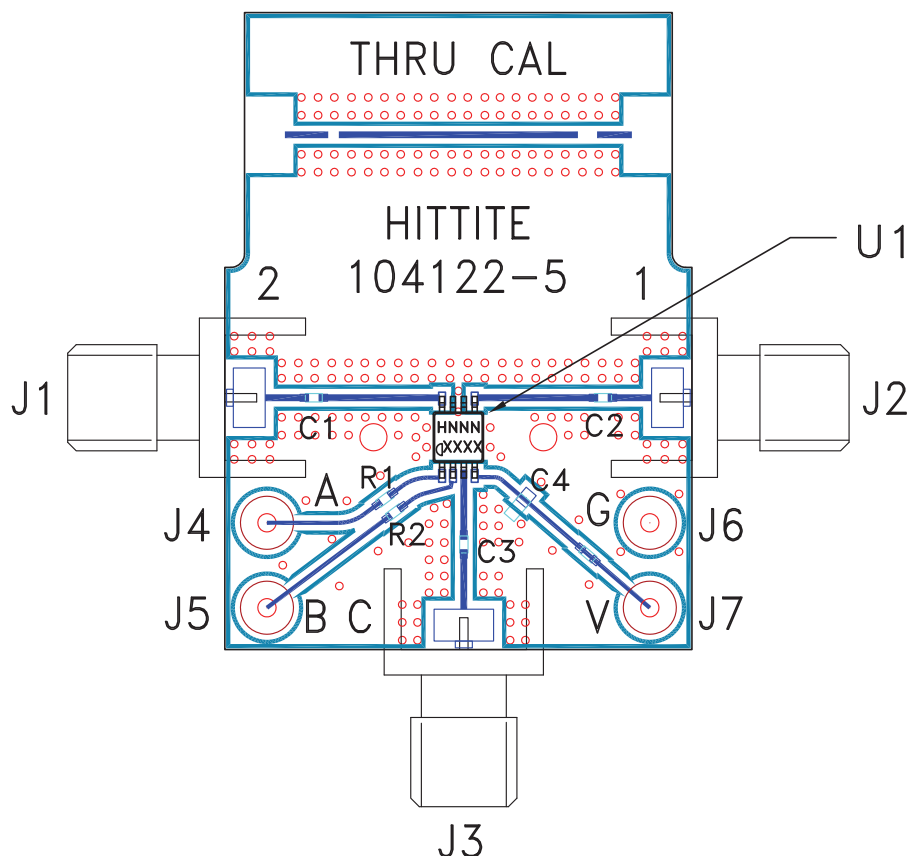
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**GaAs MMIC T/R SWITCH  
DC - 3 GHz**

**Evaluation Circuit Board**



**List of Materials for Evaluation PCB 104124 <sup>[1]</sup>**

Item	Description
J1 - J3	PCB Mount SMA RF Connector
J4 - J7	DC Pin
C1 - C3	100 pF capacitor, 0402 Pkg.
C4	10,000 pF capacitor, 0603 Pkg.
U1	HMC174MS8(E) T/R Switch
PCB <sup>[2]</sup>	104122 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 ohm impedance and the package ground leads should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.